

HCM1A4020V2

Automotive grade high current power inductors



Product features

- AEC-Q200 qualified
- High current carrying capacity
- Magnetically shielded, low EMI
- DC-DC converter applications up to 1 MHz
- Filtering applications up to Self Resonant Frequency (SRF) [See product specification table]
- 4.75 mm x 4.45 mm footprint surface mount package in a 2.0 mm height
- Moisture Sensitivity Level (MSL): 1
- Alloy powder core material

Applications

- Body electronics
 - Central body control module
 - Vehicle access control system
 - Headlamps, tail lamps and interior lighting and LED lighting
 - Heating ventilation and air conditioning controllers (HVAC)
 - Doors, window lift and seat control
- Advanced driver assistance systems
 - 77 GHz radar system
 - Basic and smart surround, and rear and front-view camera
 - Adaptive cruise control (ACC)
 - Automatic parking control
 - Collision avoidance system/ Car black box system
- Infotainment and cluster electronics
 - Active noise cancellation (ANC)
 - Audio subsystem: head unit and trunk amp
 - Digital instrument cluster
 - In-vehicle infotainment (IVI) and navigation
 - Port power/USB HUB for front and rear passengers
- Chassis and safety electronics
 - Airbag control unit
- Engine and Powertrain Systems
 - Electric pumps, motor control and auxiliaries
 - Powertrain control module (PCU)/ Engine Control unit (ECU)
 - Transmission Control Unit (TCU)

Environmental data

- Storage temperature range (Component): -55 °C to +155 °C
- Operating temperature range: -55 °C to +155 °C (ambient plus self-temperature rise)
- Solder reflow temperature: J-STD-020 (latest revision) compliant



Powering Business Worldwide

Product specifications

Part number ⁶	Part marking designator	OCL ¹ (μH) ± 20%	FLL ² (μH) minimum	I _{rms} ³ (A)	I _{sat} ⁴ (A)	DCR (mΩ) typical @ +20 °C	DCR (mΩ) maximum @ +20 °C	SRF (MHz) typical	K-factor ⁵
HCM1A4020V2-R10-R	A	0.10	0.056	16	22	3.1	4.0	350	2852
HCM1A4020V2-R22-R	B	0.22	0.123	11	17	5.5	6.6	200	2390
HCM1A4020V2-R33-R	C	0.33	0.185	8.5	12	7.5	9.0	140	1906
HCM1A4020V2-R47-R	D	0.47	0.263	7.3	11	10.5	13.0	120	1744
HCM1A4020V2-R56-R	E	0.56	0.314	7.3	10	12.0	15.0	95	1612
HCM1A4020V2-R68-R	F	0.68	0.381	6.7	9	12.5	16.0	80	1586
HCM1A4020V2-1R0-R	G	1.0	0.56	5.6	7	20	24	60	1350
HCM1A4020V2-1R2-R	H	1.2	0.67	5.3	6.8	23	28	55	1227
HCM1A4020V2-1R5-R	I	1.5	0.84	4.5	6.0	25	30	45	1137
HCM1A4020V2-2R2-R	J	2.2	1.23	4.6	5.0	40	48	40	711
HCM1A4020V2-3R3-R	K	3.3	1.85	3.1	4.0	71	85	32	786
HCM1A4020V2-4R7-R	L	4.7	2.63	2.5	3.2	98	118	27	587
HCM1A4020V2-6R8-R	M	6.8	3.8	1.7	2.6	167	192	23	511
HCM1A4020V2-100-R	N	10.0	5.6	1.6	2.2	245	281	17	342
HCM1A4020V2-150-R	O	15.0	8.4	1.3	1.8	320	384	14	316

1. Open Circuit Inductance (OCL) Test Parameters: 100 kHz, 1.0 V_{rms}, 0.0 Adc, +25 °C

2. Full Load Inductance (FLL) Test Parameters: 100 kHz, 1.0 V_{rms}, I_{sat}, +25 °C

3. I_{sat}: DC current for an approximate temperature rise of 30 °C without core loss. Derating is necessary for AC currents.

PCB layout, trace thickness and width, air-flow, and proximity of other heat generating components will affect the temperature rise. It is recommended that the temperature of the part not exceed +155 °C under worst case operating conditions verified in the end application.

4. I_{sat}: Peak current for approximately 30% rolloff @ +25 °C

5. K-factor: Used to determine B_{pp} for core loss (see graph). Bp-p = K * L * ΔI. B_{pp}: (Gauss), K: (K-factor from table), L: (Inductance in μH), ΔI (Peak to peak ripple current in Amps).

6. Part Number Definition: HCM1A4020V2-xxx-R

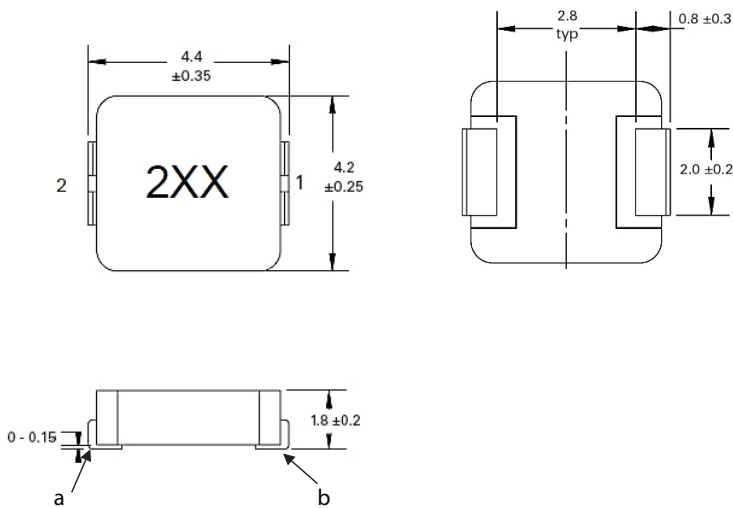
HCM1A4020V2 = Product code and size

xxx= inductance value in μH, R= decimal point,

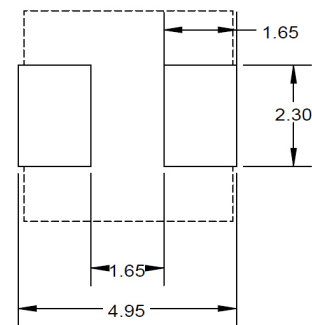
If no R is present then last character equals number of zeros

-R suffix = RoHS compliant

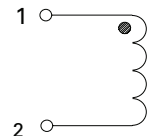
Dimensions (mm)



Recommended pad layout



Schematic



Part marking: 2xy, x=Part marking designator (see product specifications table), y=Bi-weekly date code

All soldering surfaces to be coplanar within 0.1 millimeters

Tolerances are ±0.3 millimeters unless stated otherwise

Pad layout tolerances are ±0.1 millimeters unless stated otherwise

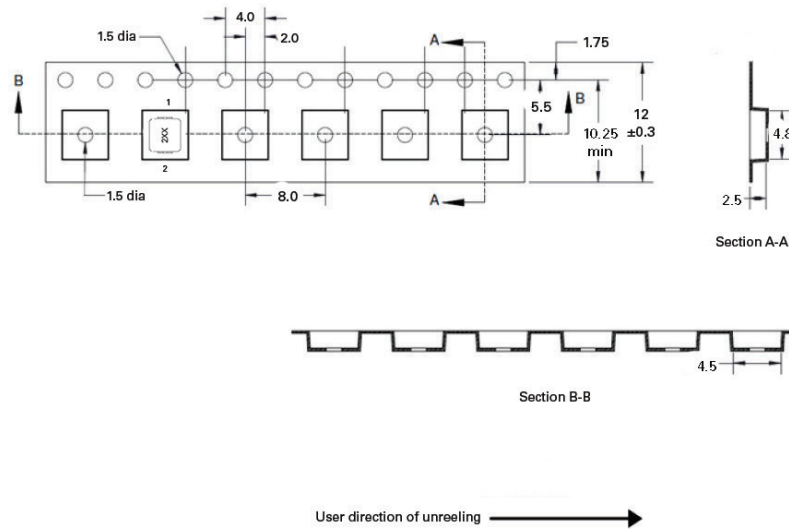
DCR measured from point "a" to point "b"

Do not route traces or vias underneath the inductor

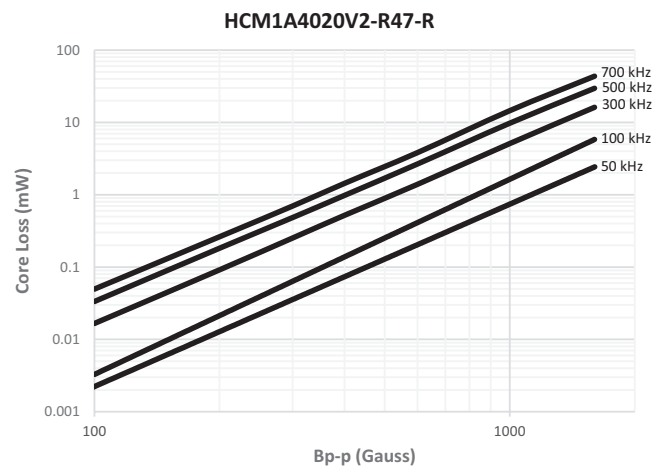
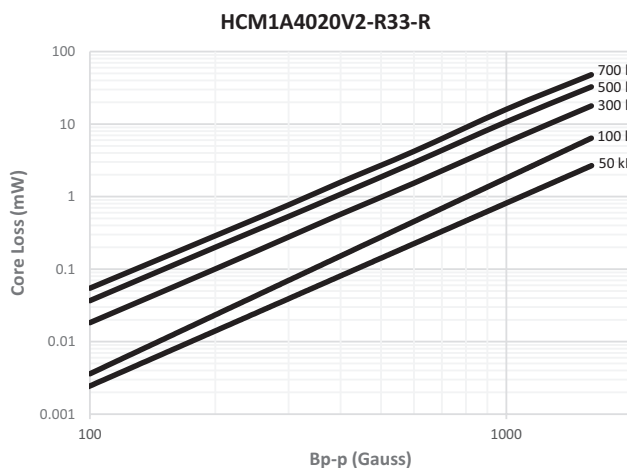
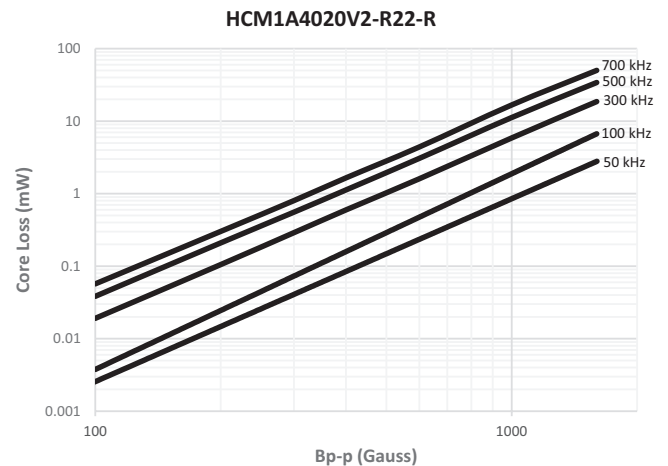
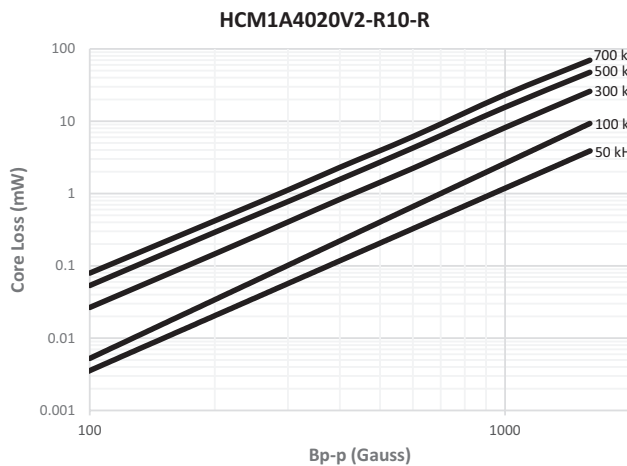
Packaging information (mm)

Drawing not to scale

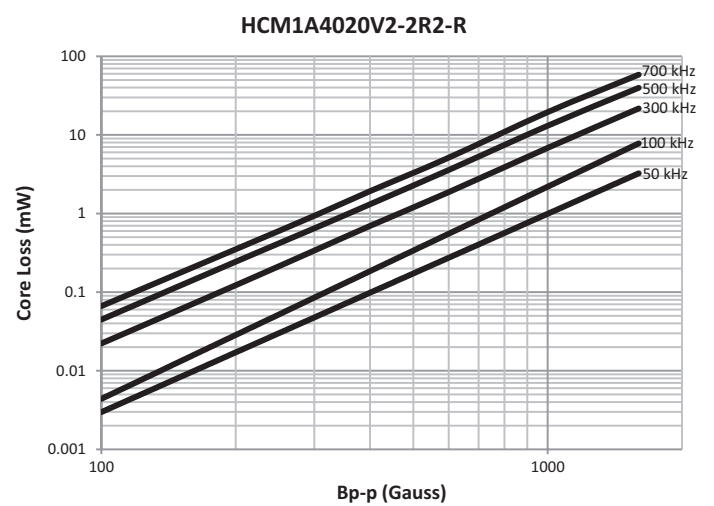
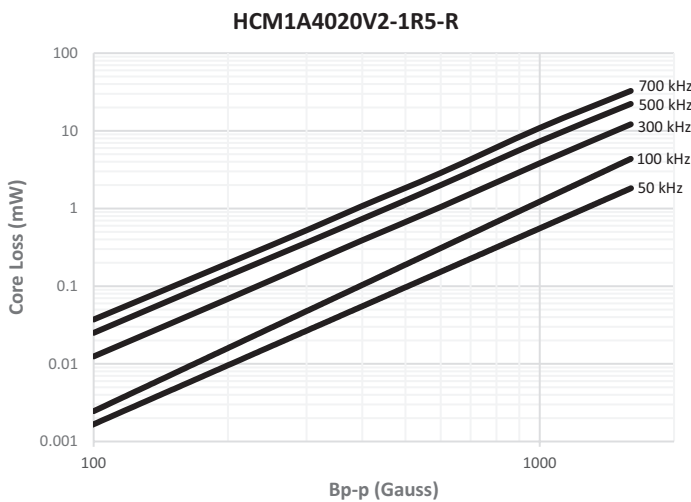
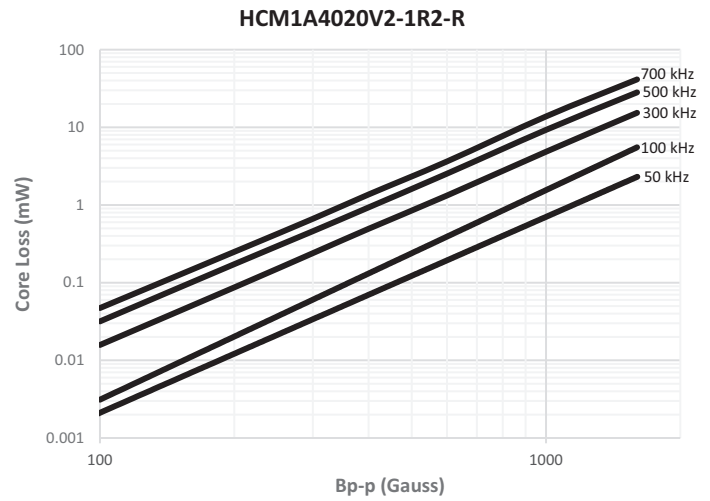
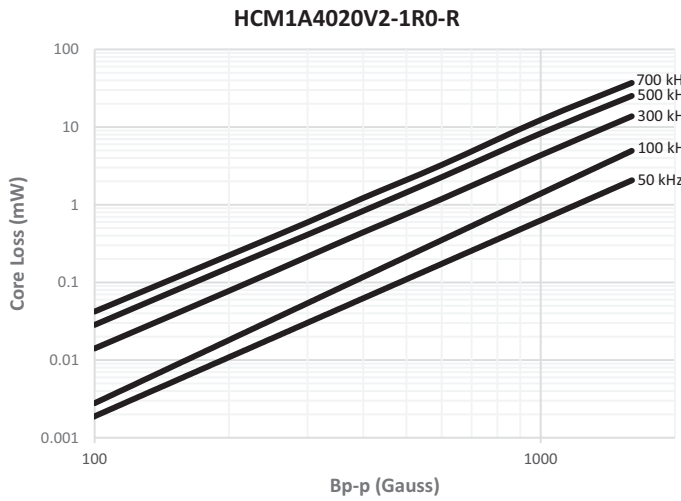
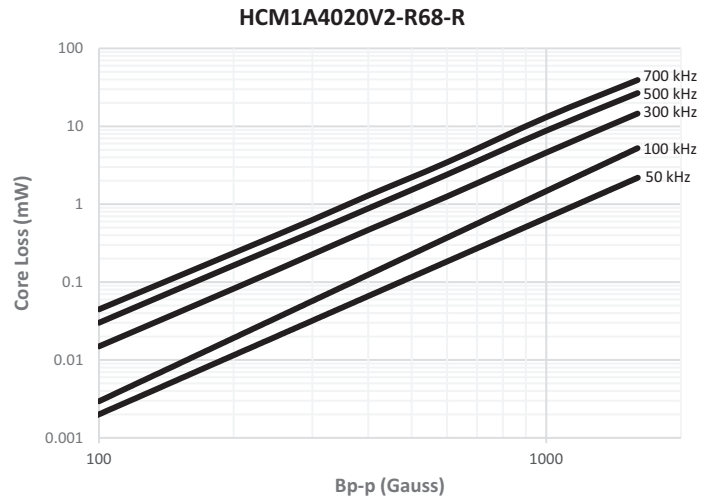
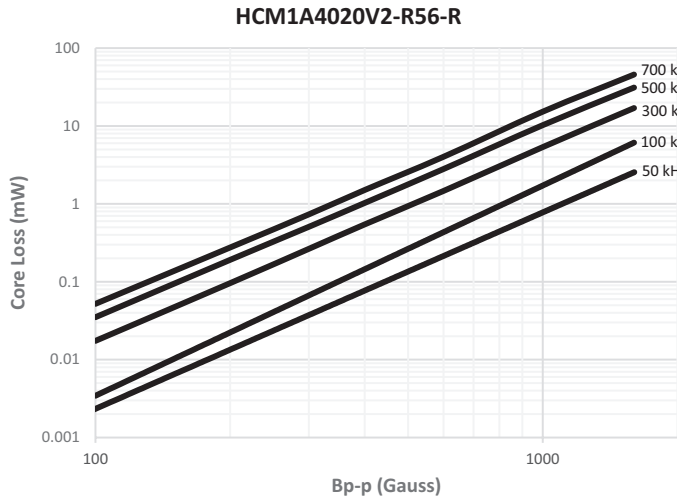
Supplied in tape and reel packaging, 3000 parts per 13" diameter reel



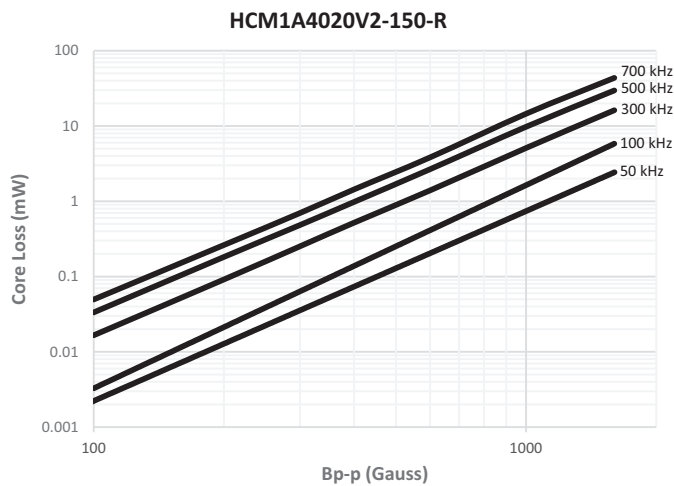
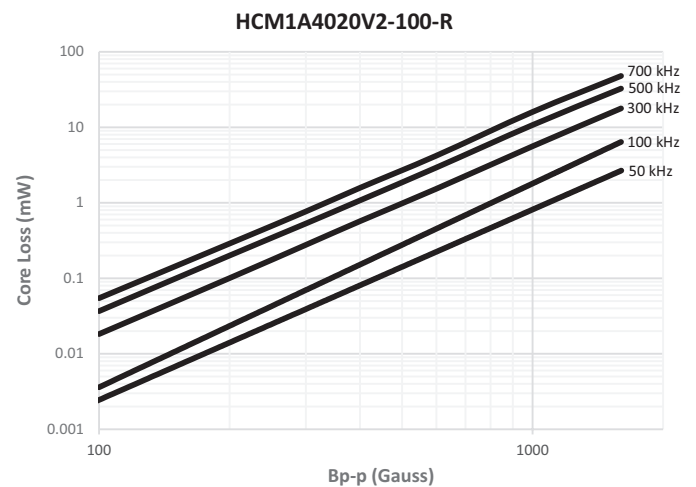
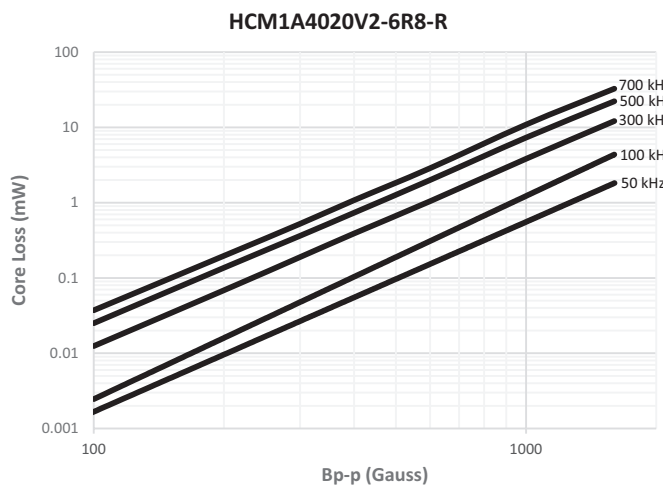
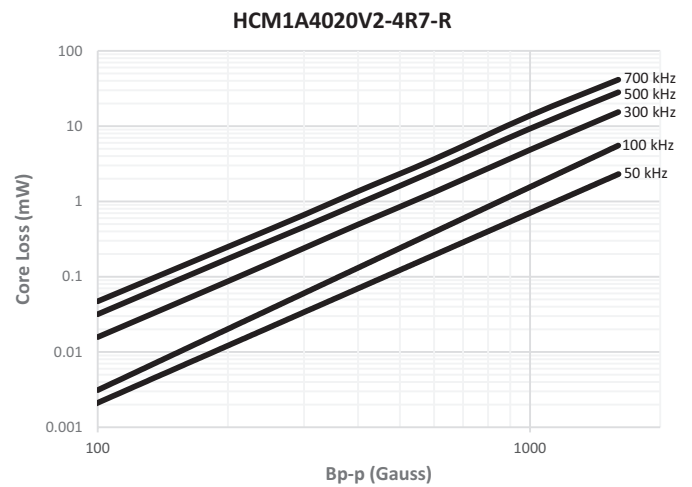
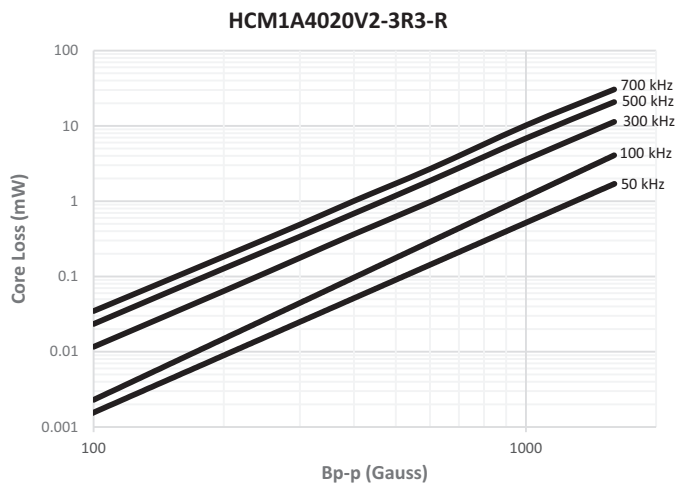
Core loss vs B_{p-p}



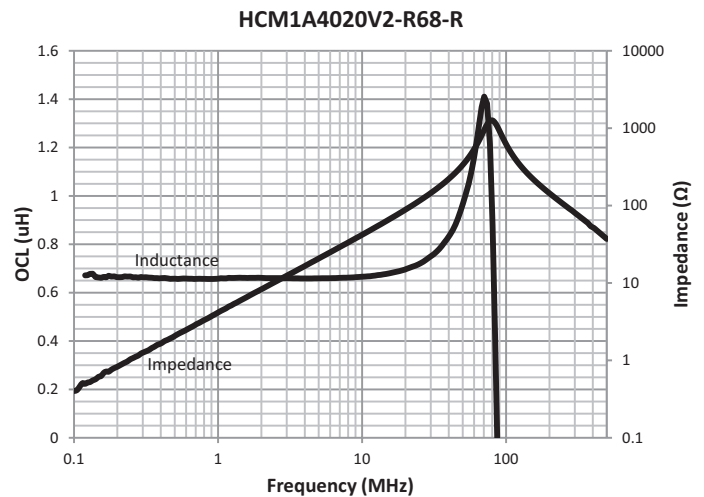
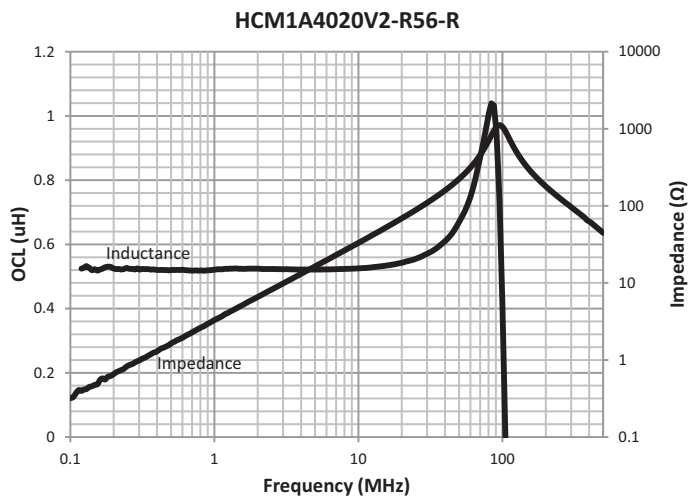
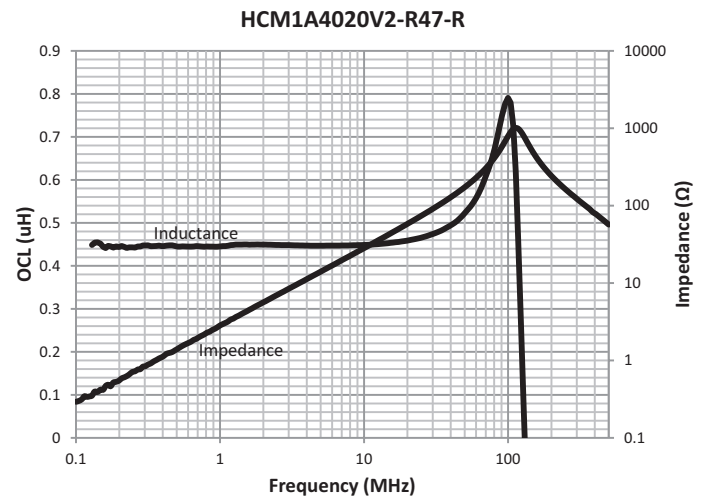
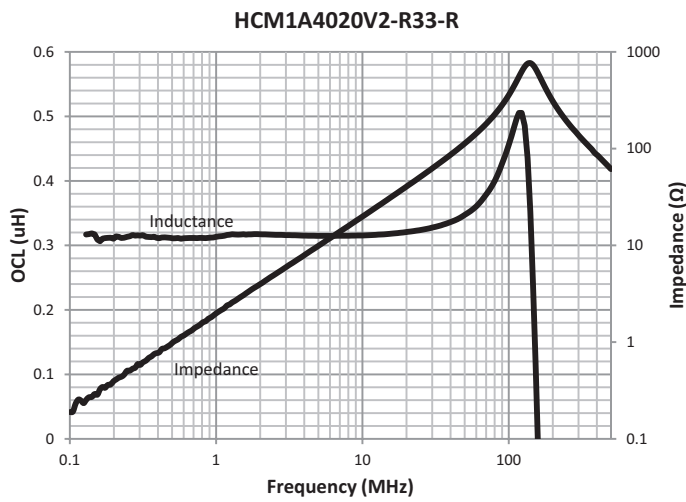
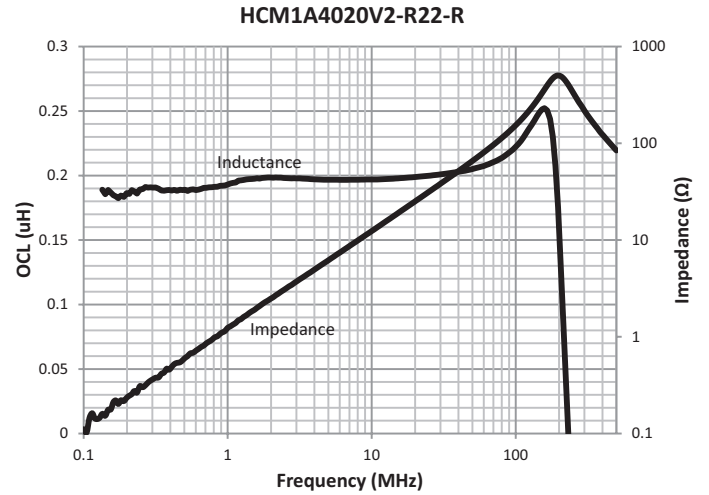
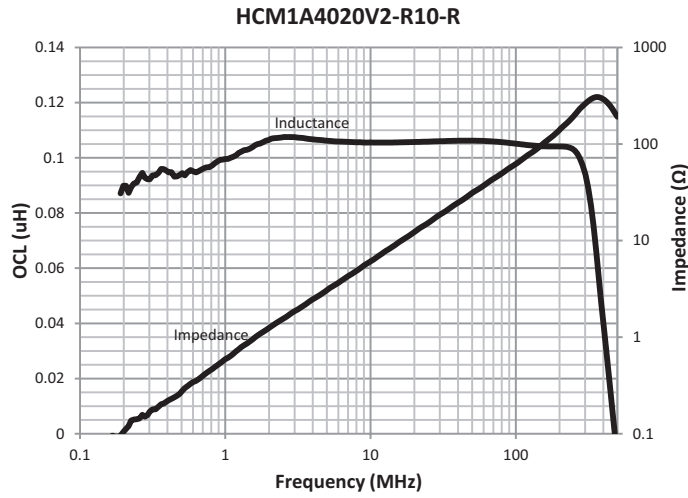
Core loss vs B_{p-p}



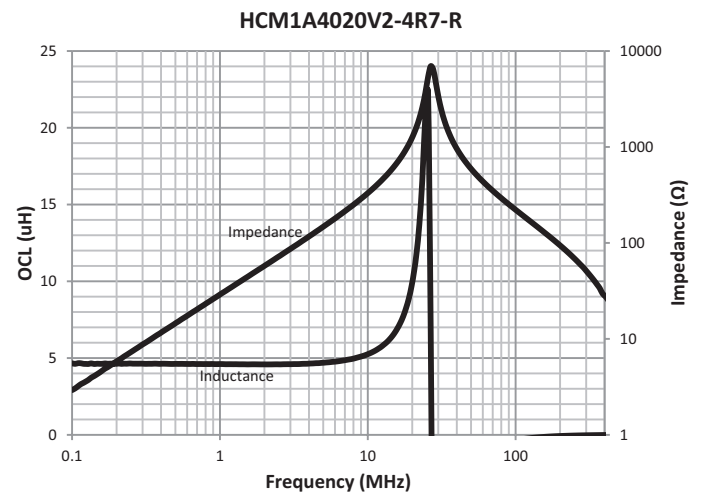
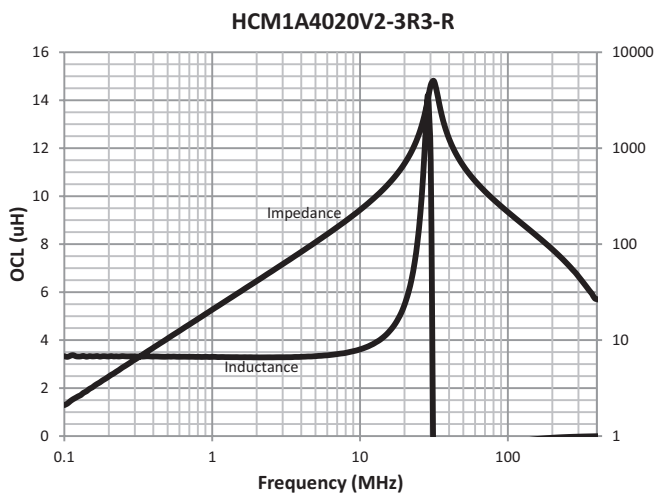
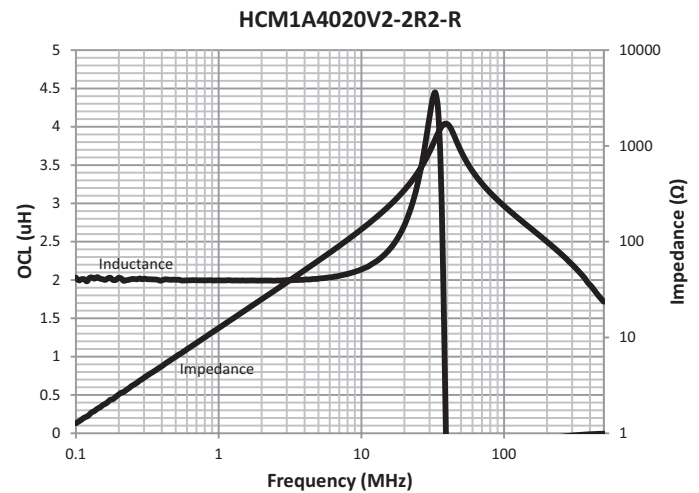
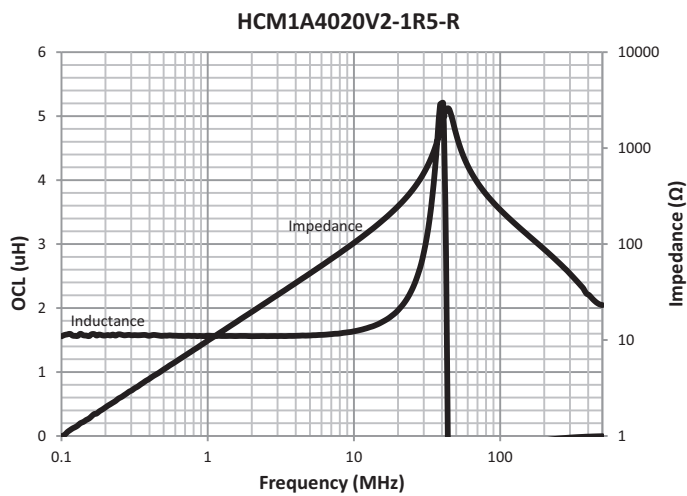
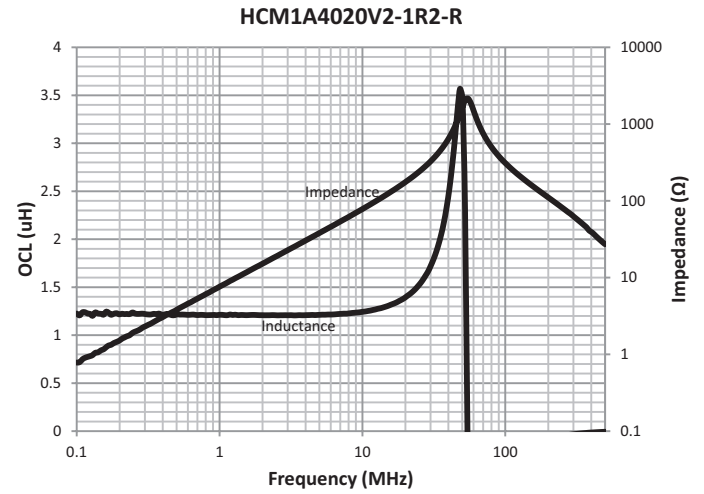
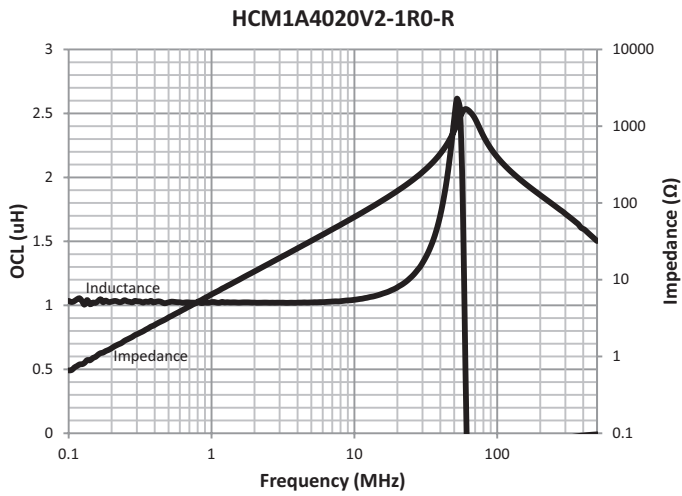
Core loss vs B_{p-p}



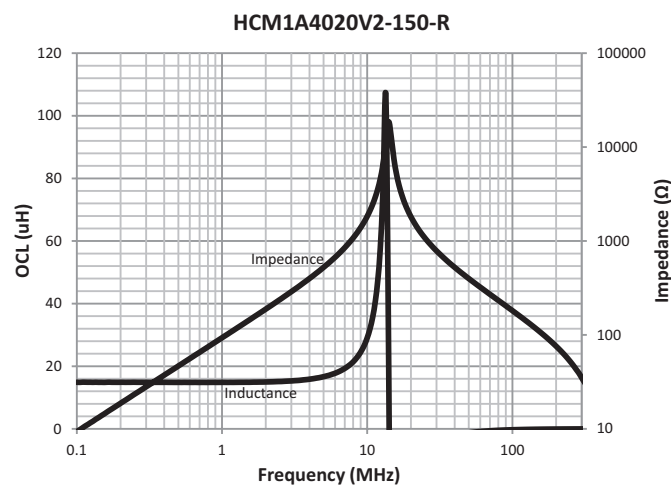
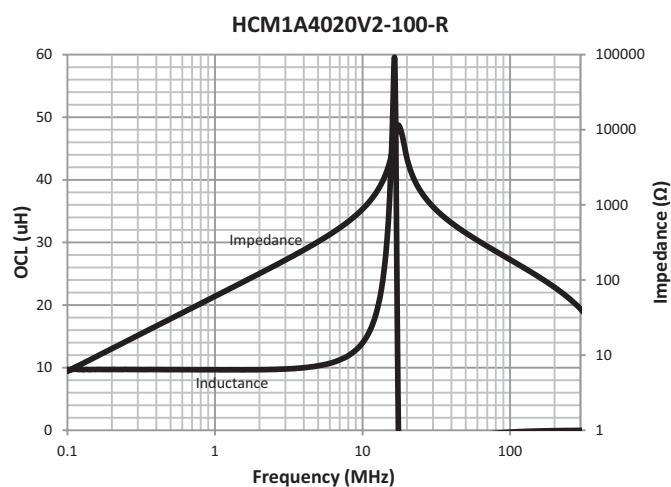
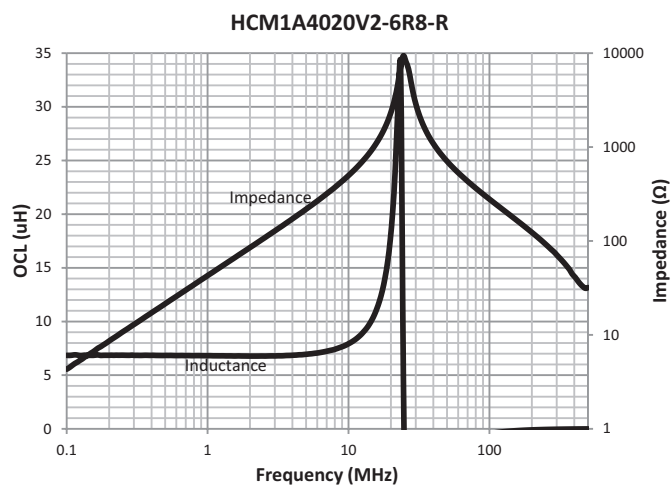
Inductance and impedance vs. frequency



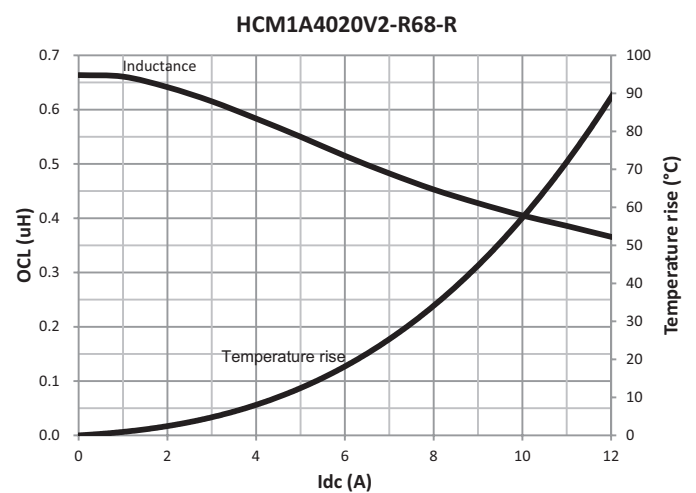
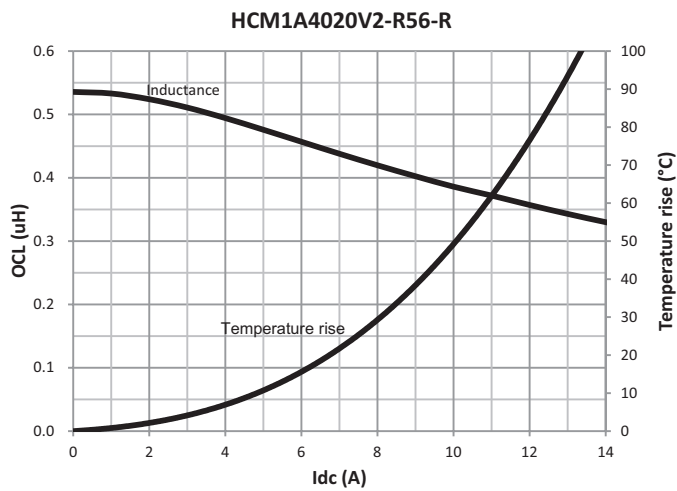
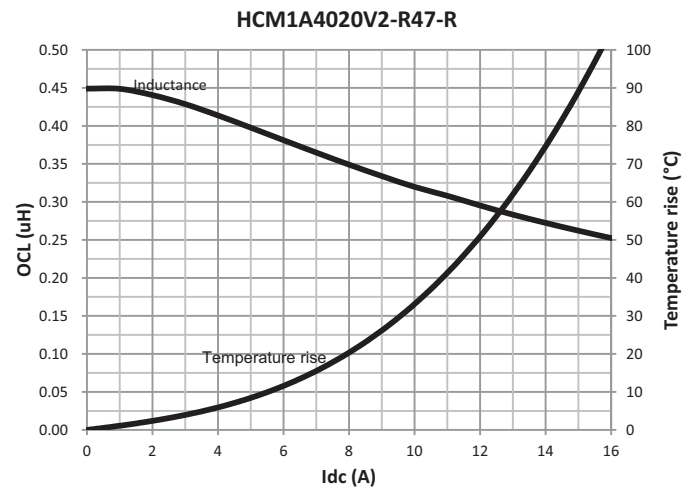
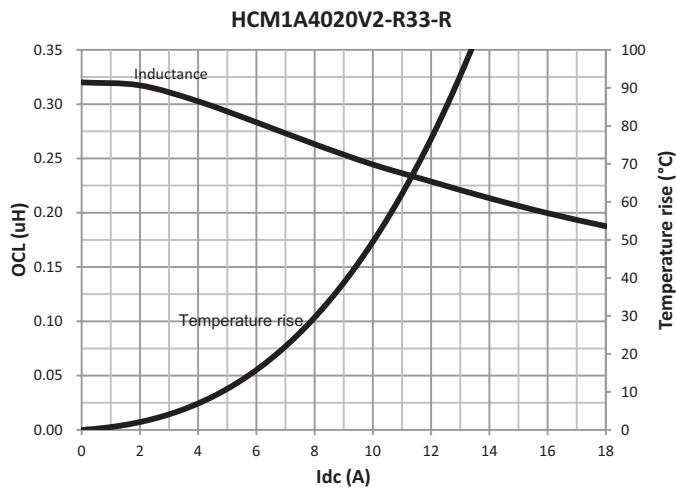
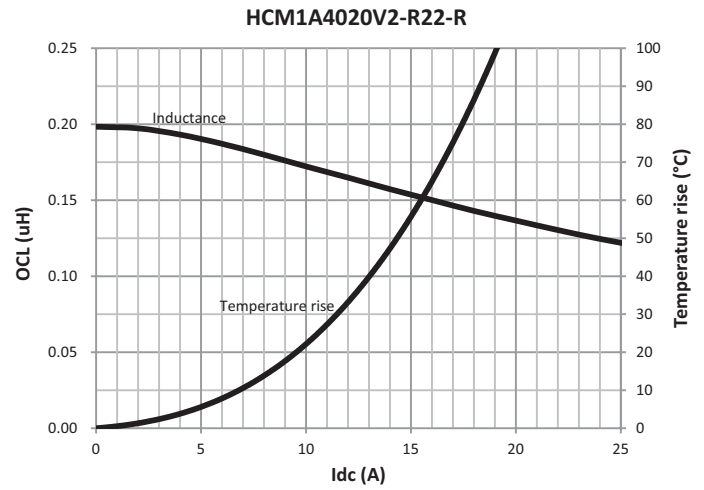
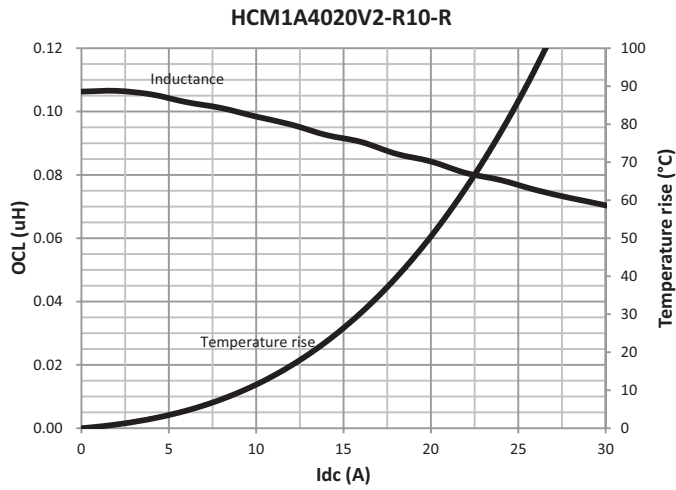
Inductance and impedance vs. frequency



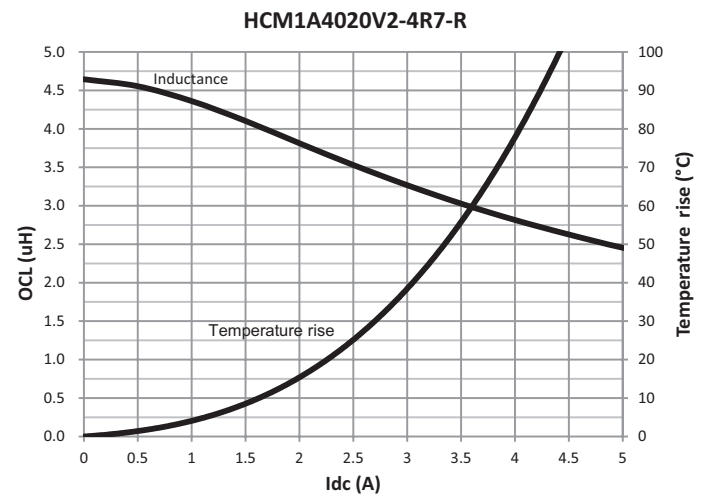
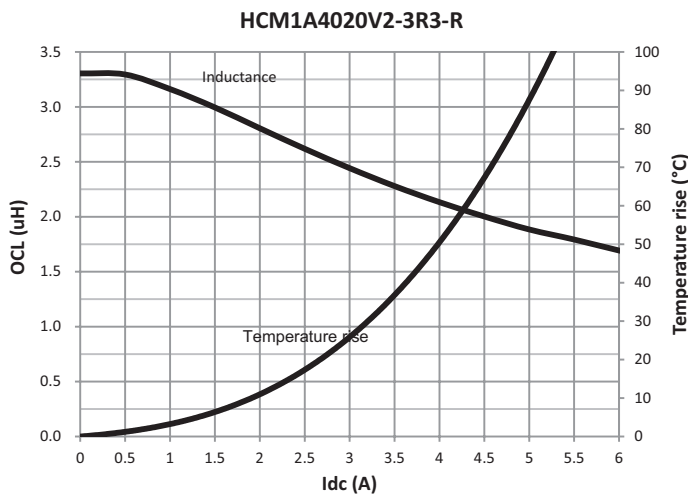
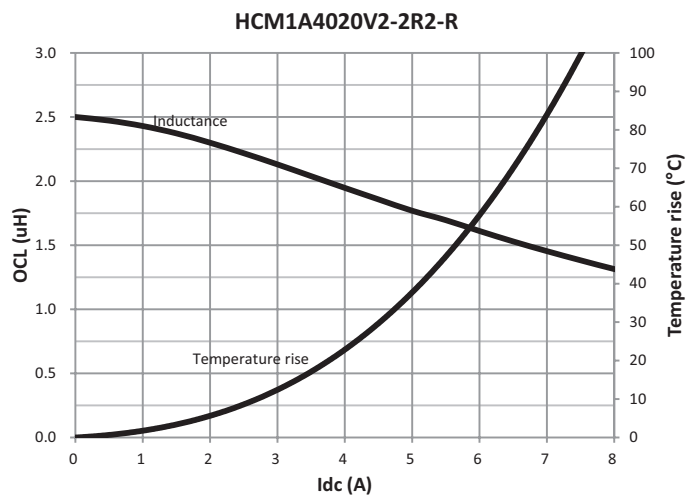
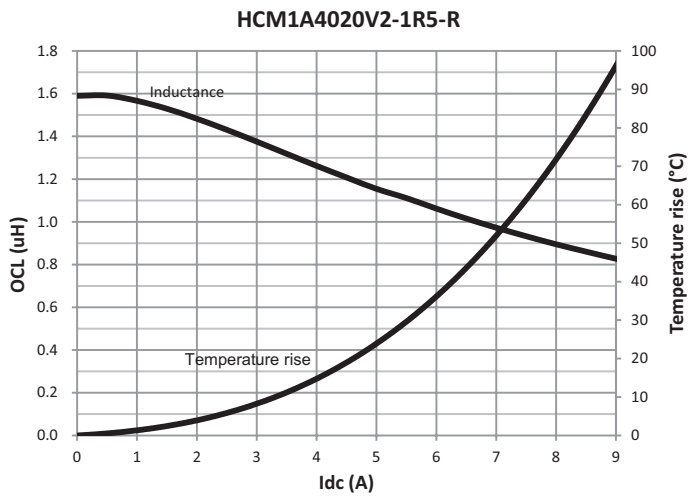
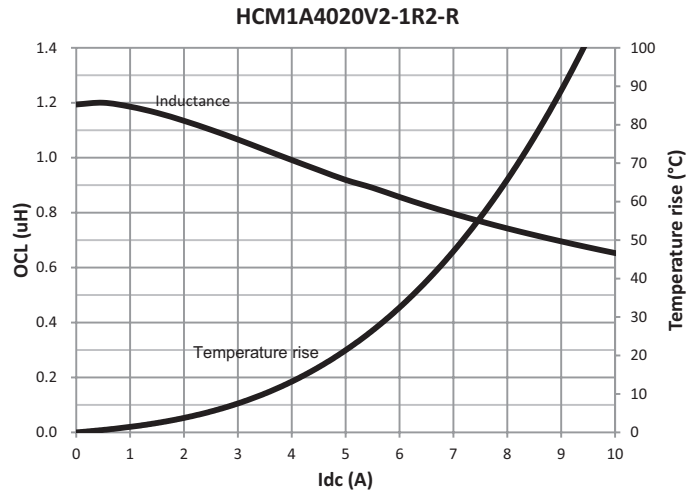
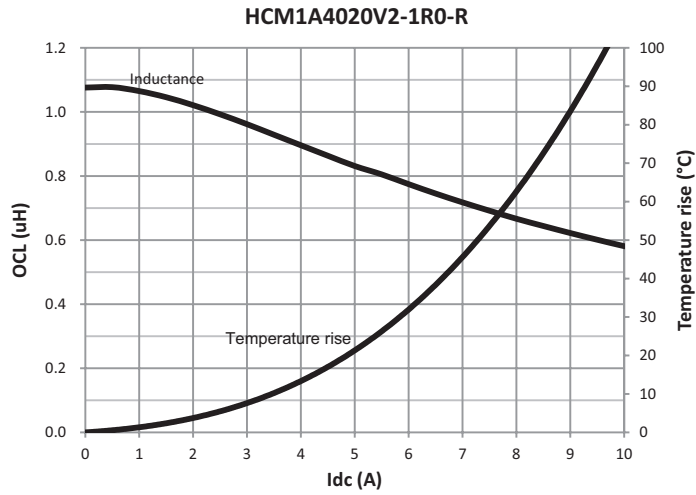
Inductance and impedance vs. frequency



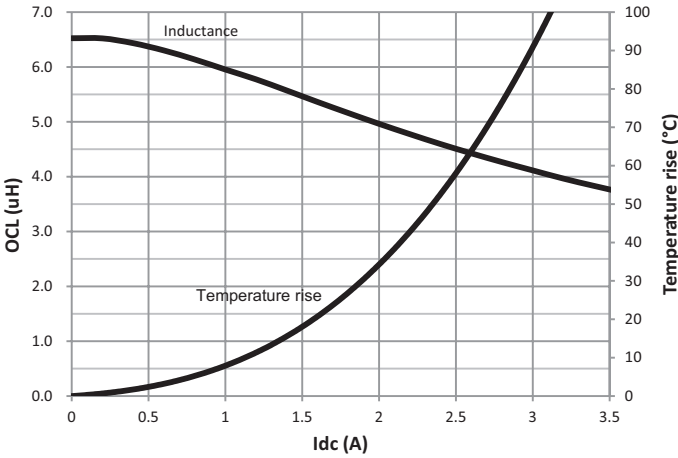
Inductance and temperature rise vs. current



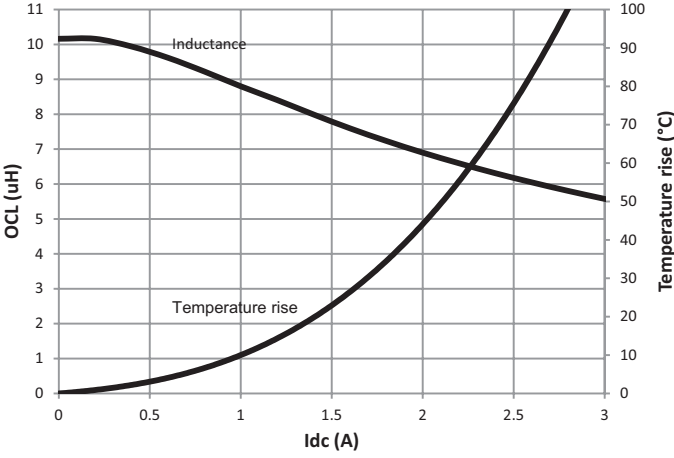
Inductance and temperature rise vs. current



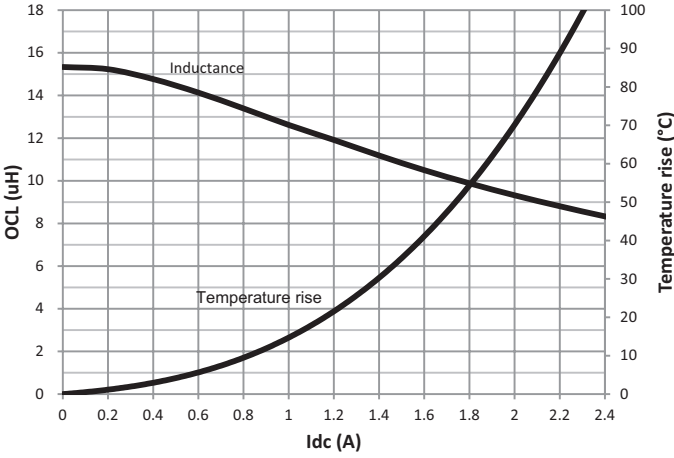
HCM1A4020V2-6R8-R



HCM1A4020V2-100-R



HCM1A4020V2-150-R



Solder reflow profile

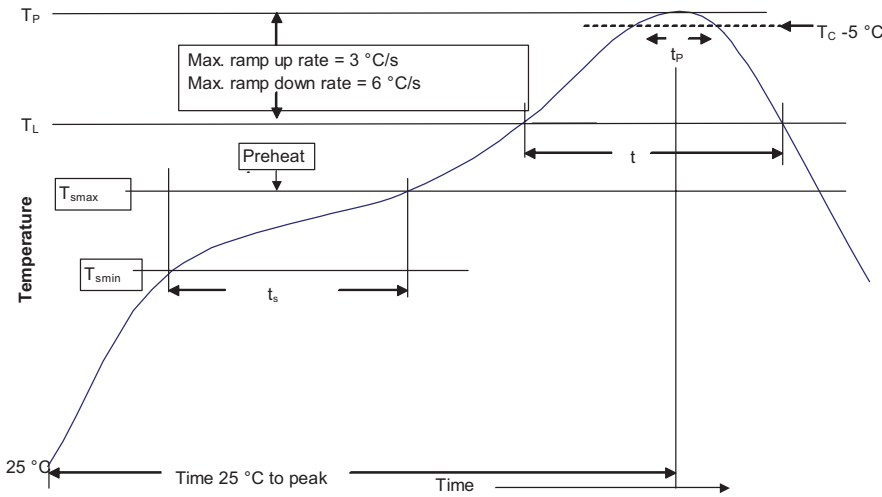


Table 1 - Standard SnPb solder (T_c)

Package thickness	Volume mm ³ <350	Volume mm ³ ≥350
<2.5 mm)	235 °C	220 °C
≥2.5 mm	220 °C	220 °C

Table 2 - Lead (Pb) Free Solder (T_c)

Package thickness	Volume mm ³ <350	Volume mm ³ 350 - 2000	Volume mm ³ >2000
<1.6 mm	260 °C	260 °C	260 °C
1.6 – 2.5 mm	260 °C	250 °C	245 °C
>2.5 mm	250 °C	245 °C	245 °C

Reference J-STD-020

Profile feature	Standard SnPb solder	Lead (Pb) free solder
Preheat and soak		
• Temperature min. (T_{smin})	100 °C	150 °C
• Temperature max. (T_{smax})	150 °C	200 °C
• Time (T_{smin} to T_{smax}) (t_s)	60-120 seconds	60-120 seconds
Average ramp up rate T_{smax} to T_p	3 °C/ second max.	3 °C/ second max.
Liquidous temperature (T_L)	183 °C	217 °C
Time at liquidous (t_L)	60-150 seconds	60-150 seconds
Peak package body temperature (T_p)*	Table 1	Table 2
Time (t_p)** within 5 °C of the specified classification temperature (T_c)	20 seconds**	30 seconds**
Average ramp-down rate (T_p to T_{smax})	6 °C/ second max.	6 °C/ second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

* Tolerance for peak profile temperature (T_p) is defined as a supplier minimum and a user maximum.

** Tolerance for time at peak profile temperature (t_p) is defined as a supplier minimum and a user maximum.

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